

Document	Issue	<b>N</b>	C1	0.1.1	Filing Date
Number	<u>Date</u>	Name	Class	Subclass	If Appropriate
6,006,694	12/28/99	DeOrnellas er al.	118	723 I	
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*E		FOREIGN PATENT DO	CUMENTS		
MARKET					
Document	Publication	n			Translation
Number	<u>Date</u>	Name	Class	Subclass	If Appropriate
EP 0421348	04/10/91	Tamura et al.	C23C	14/35	
EP 0650182	04/26/95	Rice et al.	H01J	37/32	
EP 0727807	08/21/96	Hanawa et al.	H01J	37/32	
EP 0732729	09/18/96	Kanai et al.*	H01J	37/32	
	Document Number EP 0421348 EP 0650182	Document Publication Number Date  EP 0421348 04/10/91  EP 0650182 04/26/95	Toke	FOREIGN PATENT DOCUMENTS    Document   Publication   Number   Date   Name   Class     EP 0421348   04/10/91   Tamura et al.   C23C     EP 0650182   04/26/95   Rice et al.   H01J	FOREIGN PATENT DOCUMENTS    Document   Publication   Name   Class   Subclass     EP 0421348   04/10/91   Tamura et al.   C23C   14/35     EP 0650182   04/26/95   Rice et al.   H01J   37/32

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)



Lee et al., "Patterning of Pt thin films using SiO2 mask in a high density plasma", J. Kor. Inst. Telematics & Elect., Vol.34D, No.3, pp.187 - 192 (1997).



Lieberman et al., "Plasma Sources for Thin Film Deposition and Etching", <u>Physics of Thin Films:</u> <u>Advances in Research and Development</u>, Vol. 18, Maurice H. Francombe and John L. Vossen, eds., Academic Press, Inc., San Diego, pp. 10-13, 30, 31, 52, 53, 60, 61 (1994).

H01L

21/3065

Alla a Ola 5/27/2003

JP 07221070 08/18/95 Kadomuro Shingo

Examiner

Date Considered

Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

\* Cited by the Examiner in the parent application.

FORM PTO-1449 (Equivalent)

U.S. Department of Commerce Patent and Trademark Office

U.S. Application Serial No.

Not yet assigned

O9/216, 785

Atty. Docket No. AM-2090P1.C1/2090.C2

INFORMATION DISCLOSURE

(Use several sheets if necessary)

STATEMENT BY APPLICANT

Jeng H. Hwang et al. Applicants

June 29, 2001 Filing Date

<u>/7</u>63 Group

<del> </del>			U. S. PATENT DOCU			EII D
Examiner Initial	Document Number	Issue <u>Date</u>	Name	Class	Subclass	Filing Date  If Appropriate
40	5,110,408	05/05/92	Fujii et al.	156	643	
1	5,419,029	05/30/95	Raaijmakers	29	447	
<del> </del>	5,569,363	10/29/96	Bayer et al.	204	192.32	
1	5,599,403	02/04/97	Kariya et al.	136	258	
	5,614,055	03/25/97	Fairbairn et al.	156	345	
1	5,641,375	06/24/97	Nitescu et al.	156	345	
1	5,685,941	11/11/97	Forster er al.	156	345	
	5,686,339	11/11/97	Lee et al.*	437	52	
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1	5,800,688	09/01/98	Lantsman et al.	204	298.11	
AND	5,837,057	11/17/98	Koyama et al.	118	723 VE	

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